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## Magnetic and electrical properties of $\text{Mn}_2\text{Sb}_{1-x}\text{Z}_x$ ( $\text{Z} = \text{Ge}, \text{Sn}$ ) under high pressures and high magnetic fields

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### Abstract:

High pressures and high magnetic field effects on magnetic and electrical properties of polycrystalline  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$ ,  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  were investigated. These compounds showed a first-order magnetic transition between the ferrimagnetic (FRI) and antiferromagnetic (AFM) phases for 150–250 K temperature range in a zero magnetic field. The pressure dependence of the AFM/FRI transition temperature was estimated to be  $-5.1 \times 10^{-2} \text{ GPa}^{-1}$  for  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$ . The electrical resistivity changed abruptly by 50% for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and by 71% for  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  at the transition temperature. We confirmed the negative magnetoresistance over 60% for the Sn-substituted compounds.

**Keywords:**  $\text{Mn}_2\text{Sb}$ , first-order magnetic transition, pressure effect, negative magnetoresistance

### I. Introduction

$\text{Mn}_2\text{Sb}$  compound with a  $\text{Cu}_2\text{Sb}$ -type tetragonal structure (space group:  $\text{P4/nmm}$ ) is ferrimagnetic (FRI) at temperatures below  $T_C \sim 550 \text{ K}$ .<sup>1–3)</sup> The crystal and spin structures are shown in Fig. 1.<sup>3)</sup> There are two crystallographically non-equivalent sites for Mn atoms, Mn1 (2a-site) and Mn2 (2c-site), which are tetrahedrally and octahedrally surrounded by Sb atoms. The Sb atom occupies the 2c-site. Neutron diffraction study shows the presence of triple layers (Mn2-Mn1-Mn2) along the  $c$ -axis and antiparallel magnetic moments on Mn1 and Mn2. The magnetic moments of Mn atoms are  $2.1\mu_B/\text{Mn1}$  and  $3.9\mu_B/\text{Mn2}$ , leading to the FRI state in  $\text{Mn}_2\text{Sb}$ .<sup>2)</sup>

The substitution of various elements (V, Cr, Co, Cu and Zn) for Mn, as well as (As, Ge and Sn) for Sb, results in a first-order magnetic transition from the FRI to an antiferromagnetic (AFM) state at the transition temperatures  $T_t$  ( $\sim 100\text{--}300 \text{ K}$ ) for cooling process.<sup>1–17)</sup> The moments of all triple layers are parallel in the FRI state whereas the arrangement is antiparallel in the AFM state.<sup>2,3)</sup> The lattice parameters, the magnetization  $M$ , the electrical resistivity  $\rho$ , *etc.* of these substitution compounds change abruptly and are accompanied by the FRI-AFM transition.<sup>4–7,15,16)</sup> In addition, the magnetoresistance and the magnetostrictive effects of these compounds were observed at temperatures below  $T_t$  and were accompanied by a field-induced AFM/FRI transition.<sup>5–7,15,16)</sup> Therefore, these compounds have attracted attention as magnetic field-controlled materials.

Recently, the thermal FRI/AFM transition in  $\text{Mn}_{1.85}\text{Co}_{0.15}\text{Sb}^6)$  and  $\text{Mn}_{1.8}\text{Co}_{0.2}\text{Sb}^{7,14)$  was reported to be arrested by applying a magnetic field  $B$ , called “kinetic arrest effect (KA effect)”<sup>6)</sup> or “thermal transformation arrest (TTA) effect”. On the other hand, Shimada *et al.*<sup>15)</sup> and Koyama *et al.*<sup>16)</sup> reported that  $\text{Mn}_2\text{Sb}_{1-x}\text{Z}_x$  ( $\text{Z} = \text{Ge}$  or  $\text{Sn}$ ) does not exhibit the TTA effect. The substitution of Co for Mn as well as Ge and Sn for Sb results in a lattice contraction and a first-order magnetic transition from the FRI to an antiferromagnetic (AFM).<sup>15,16)</sup> Therefore, in order to clarify the origin of the TTA effect and to estimate the potential of  $\text{Mn}_2\text{Sb}_{1-x}\text{Z}_x$  for applications, it is necessary to clarify the magnetic and

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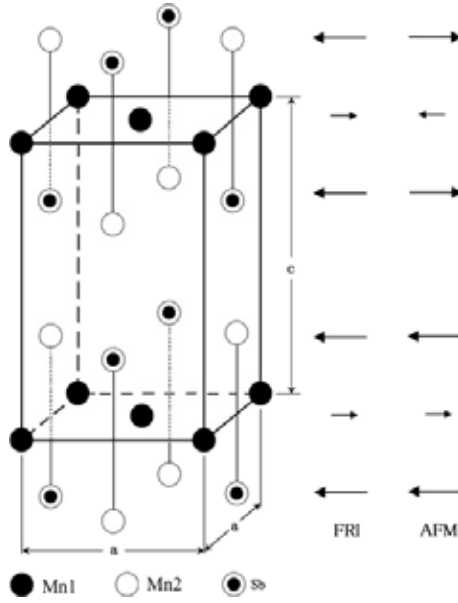


Fig. 1. Crystal structure and arrangement of Mn1 and Mn2 moments in the ferrimagnetic (FRI) and the antiferromagnetic (AFM) states in  $\text{Mn}_2\text{Sb}$  based compound. The length of the arrow represents the magnitude of the magnetic moment of the atom.<sup>3)</sup>

electrical properties for these compounds in high magnetic fields and high pressures. In this report, we present the experimental results of the magnetic properties of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  under high pressures up to 1 GPa and the electrical properties of  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$  ( $x = 0.08$  and  $0.15$ ) under high magnetic fields up to 16 T.

## 2. Experimental

Polycrystalline  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$ ,  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  were prepared by arc-melting a mixture of nominal amounts of pure elements (Mn, 3N; Co, 3N; Sb, 4N) in an argon atmosphere. The obtained button-shaped ingots were turned over and re-melted several times. After that, the ingot was annealed at 923 K for 24 h in a quartz tube with a vacuum and then slowly cooled to room temperature. The obtained sample was confirmed to be a single phase of a  $\text{Cu}_2\text{Sb}$ -type structure by X-ray powder diffraction (XRD) measurements at room temperature.

The magnetization  $M$  measurements were carried out using a superconducting quantum interference device (SQUID) magnetometer (Quantum Design) in the temperature  $T$  range from 10 to 330 K and magnetic fields  $B$  up to 5 T. The electrical resistivity  $\rho$  was measured by using a standard four-probe technique for  $4.2 \leq T \leq 280$  K and  $0 \leq B \leq 16$  T with an 18-T superconducting magnet. The initial permeability  $\mu$  was measured by an AC transformer method using a piston-cylinder type pressure cell under hydrostatic pressures  $P$  up to 1 GPa for  $77 \leq T \leq 400$  K.

## 3. Results and discussion

Figure 2 shows the temperature dependence of the magnetization of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  for  $B = 0.1$  T and 5 T. Here, the measurements were made in field cooling (FC; solid curve), field cooled warming (FCW; solid curve) and field warming after zero-field cooling (ZFCW; broken curve). The data of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  for  $B = 0.1$  T show that a first-order phase transition from a FRI to an AFM phases occurs in the vicinity of 230 K ( $= T_t$ ) with a thermal hysteresis of approximately 15 K. This transition temperature  $T_t$  of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  is larger than that ( $T_t = 172$  K) of  $\text{Mn}_2\text{Sb}_{0.95}\text{Ge}_{0.05}$ . When a magnetic field of 5 T was applied,  $T_t$  of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  decreases to 210 K, and the width of the hysteresis did not change and was approximately 15 K. This phenomenon is different from that of  $\text{Mn}_2\text{Sb}_{0.95}\text{Ge}_{0.05}$ . The width of the hysteresis of  $\text{Mn}_2\text{Sb}_{0.95}\text{Ge}_{0.05}$  at  $T_t$  expands by applying magnetic fields.<sup>16)</sup> As seen in Fig.2,  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  does not exhibit the TTA effect observed in  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$ <sup>7,13,14)</sup>.

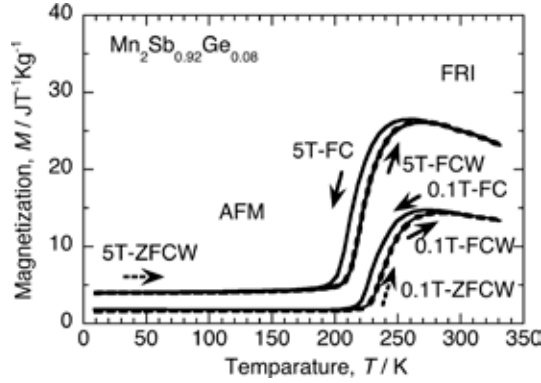


Fig. 2. Temperature dependence of the magnetization of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  for  $B = 0.1$  T and 5 T. The measurements were made in field cooling (FC; solid curve), field cooled warming (FCW; solid curve) and field warming after zero-field cooling (ZFCW; broken curve).

Figure 3 shows the temperature dependence of the initial AC permeability  $\mu$  ( $\mu$ - $T$  curve) of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  under various pressures up to 1 GPa. Here, the measurements were carried out for heating process. The first-order AFM/FRI transition temperature for heating process,  $T_t^*$ , was estimated by the inflection point on the  $\mu$ - $T$  curve for heating process. In this figure, the vertical arrows indicate the determined  $T_t^*$  in various pressures.

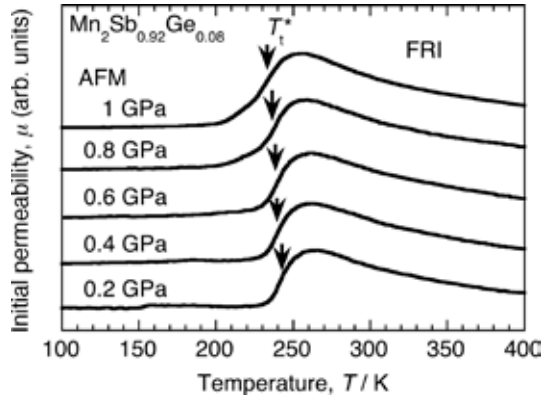


Fig. 3. Temperature dependence of the initial AC permeability  $\mu$  ( $\mu$ - $T$  curve) of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  under various pressures up to 1 GPa. The measurements were carried out for heating process. The vertical arrows indicate the determined AFM/FRI transition temperature for heating process  $T_t^*$ .

Figure 4 shows the pressure dependence of the AFM/FRI transition temperature for heating process. As seen in this figure,  $T_t^*$  decreases linearly with increasing a pressure  $P$ , and the line in this figure is calculated by the least-square method using a linear function. The AFM/FRI transition temperature for heating process under 0.1 MPa and a zero field was estimated to be 246 K by the linear extrapolation of  $T_t^*$  vs.  $P$ . The pressure dependence of  $T_t^*$  was estimated to be  $d\ln T_t^*/dP = -5.1 \times 10^{-2} \text{ GPa}^{-1}$ . This result on the pressure effect with the lattice contraction indicates that the AFM interaction is suppressed by applying a pressure, but the FRI interaction is enhanced. This result is inconsistent with the previous report<sup>16)</sup> on the substitution effect with the lattice contraction for  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$ . According to a report by Koyama *et al.*, the lattice parameters  $a$  and  $c$  of the Ge-substituted  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$  compound contract with increasing  $x$ , and the AFM/FRI transition temperature  $T_t$  increases while the Curie temperature  $T_C$  decreases.<sup>16)</sup> Their result indicates that the AFM interaction is enhanced but the FRI interaction is suppressed with the lattice contraction by the substitution of Ge for Sb in  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$ .

For Co-substituted compounds,  $d\ln T_t^*/dP$  was estimated to be  $-0.16 \text{ GPa}^{-1}$  for  $\text{Mn}_{1.9}\text{Co}_{0.1}\text{Sb}^{18)}$  and  $+0.3 \text{ GPa}^{-1}$  for  $\text{Mn}_{1.8}\text{Co}_{0.2}\text{Sb}^{19)}$ . The absolute value of  $d\ln T_t^*/dP$  for  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  is much smaller than that for  $\text{Mn}_{1.9}\text{Co}_{0.1}\text{Sb}$  or

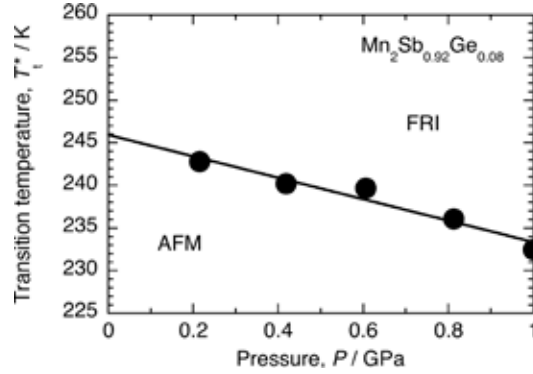


Fig. 4. Pressure dependence of the AFM/FRI transition temperature for heating process.

$\text{Mn}_{1.8}\text{Co}_{0.2}\text{Sb}$ . Considering the substitution and pressure effects as mentioned above, the AFM/FRI transition is probably due to modification of hybridization among Mn-3d, Sb-p and Ge-p electrons as well as simple change of the distance among magnetic Mn ions.

Figure 5 shows the temperature dependence of the electrical resistivity  $\rho$  ( $\rho$ - $T$  curve) of  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  (a) and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  (b) for a zero magnetic field and  $B = 16$  T. Here, ZFC and ZFW mean zero-field cooling and zero-field-warming measurements, respectively. A first-order magnetic transition from a FRI (low resistivity) to an AFM (high resistivity) states occurs with decreasing temperature for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  under a zero field and for  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  under 0 and 16 T. The broken arrows in this figure indicate the determined AFM/FRI transition temperature  $T_t$ . For  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  under a zero magnetic field,  $\rho$  changes abruptly by 50% ( $=[\rho(173 \text{ K}) - \rho(122 \text{ K})]/\rho(173 \text{ K})]=\Delta\rho/\rho$ ) in the vicinity of  $T_t = 150$  K. On the other hand,  $\Delta\rho/\rho$  of  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  under a zero magnetic field was estimated to be 71% in the vicinity of  $T_t = 183$  K. These values of  $\Delta\rho/\rho$  for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  are consistent with that of a previous report for  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$ .<sup>11,16)</sup> When a high magnetic field of 16 T was applied to  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$ , the AFM/FRI magnetic transition disappeared even at 4.2 K, indicating that the FRI state is stable for  $4.2 \leq T \leq 280$  K.

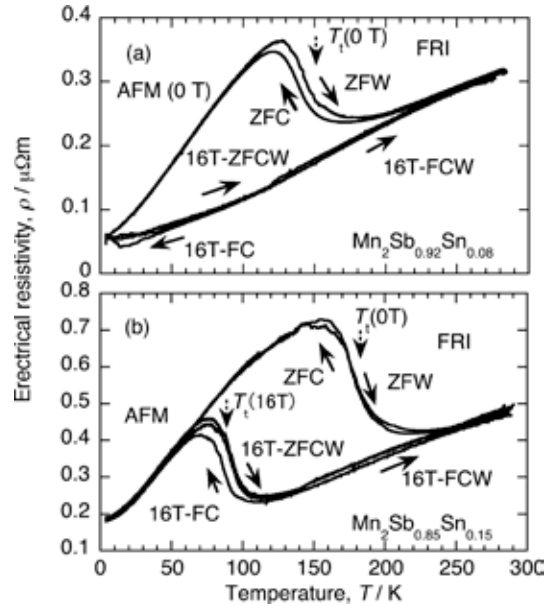


Fig. 5. Temperature dependence of the electrical resistivity  $\rho$  of  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  (a) and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  (b) for a zero magnetic field and  $B = 16$  T. The measurements were made in zero-field cooling (ZFC), zero-field warming (ZFW), field cooling (FC), field cooled warming (FCW) and field warming after zero-field cooling (ZFCW). The broken allows indicate the determined transition temperature  $T_t$  between the AFM and FRI phases.

Figure 6 shows the magnetic field dependence of the transverse magnetoresistance ratio  $\Delta\rho/\rho(0)$  [ $=(\rho(0) - \rho(B))/\rho(0)$ ] for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  at 100 K (a) and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  at 144 K (b) in magnetic fields up to 16 T. The measurements were made in field increasing process. A large negative magnetoresistance was observed, when a magnetic field of  $B = 16$  T was applied. The change in  $\Delta\rho/\rho$  was over  $-60\%$  under our conditions. The obtained values of  $\Delta\rho/\rho$  were larger than that of  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$ <sup>15)</sup> and of  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$ <sup>11)</sup>. Considering previous results, the negative magnetoresistance relates closely to the metamagnetic transition.<sup>11,15)</sup>

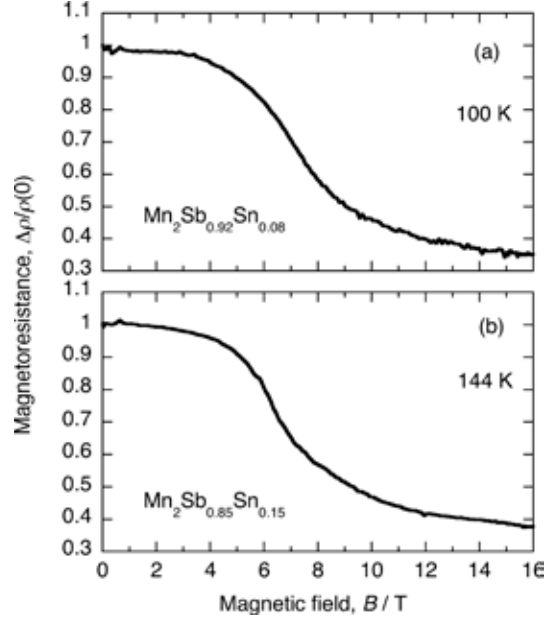


Fig. 6. Magnetic field dependence of the transverse magnetoresistance  $\Delta\rho/\rho(0)$  for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  at 100 K (a) and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  at 144 K (b) in magnetic fields up to 16 T. The measurements were made in field increasing process.

The AFM/FRI transition temperatures  $T_t$  of  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$  and  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$  decrease by applying a magnetic field. When a magnetic field is applied to these systems, the decrease of the Gibbs free energy of the FRI phase is larger than that of the AFM phase because of a gain in the Zeeman energy. This leads that the AFM/FRI transition temperature decreases with increasing magnetic fields. The decrease of  $T_t$  by applying magnetic fields is similar to that of  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$ .<sup>6,7,13,14)</sup> However, we could not observe any characteristic property of the TTA effect for  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$  for  $B \leq 5$  T and  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$  for  $B \leq 16$  T. In  $\text{Mn}_2\text{Sb}_{1-x}\text{Ge}_x$ . The value of magnetization  $M$  for FCW at 5 T (5T-FCW; solid curve) was same value for ZFCW at 5 T (5T-ZFCW; broken curve), as shown in Fig. 2. This behavior is quite different from that of  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$ . In  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$ , the value of  $M$  for FCW at 5 T is much larger than that for ZFCW at 5 T.<sup>6,7,13)</sup> In addition, the  $\rho$ - $T$  curves of  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  for  $B = 16$  T are traced on those for  $B = 0$  T at low temperature in the AFM phase; that is, the value of  $\rho$  at low temperature in the AFM phase is independent on the cooling process under a magnetic field, as seen in Fig. 5.

In contrast to the obtained results on  $\text{Mn}_2\text{Sb}_{1-x}\text{Sn}_x$ , the values of  $\rho$  of  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$  at the temperatures (AFM phase) below  $T_t$  depend strongly on the cooling process under a magnetic field.<sup>6,7)</sup> This reason is that a residual FRI phase (metastable phase) exists in the AFM phase (stable phase) under a magnetic field even at low temperature, and the content of the residual FRI phase depends strongly on the intensity of the magnetic field.<sup>6,7,13,14)</sup> This behavior of  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$  is thought to be due to the critically slow dynamics induced by the magnetic field, which is called the TTA effect induced by a magnetic field.<sup>6)</sup> Koyama *et al.* suggested that the TTA effect under a magnetic field was mainly due to the instability of the magnetic states rather than the structural or elastic properties.<sup>13-17)</sup> The results of first-principals total-energy calculations for  $\text{Mn}_{2-x}\text{Co}_x\text{Sb}$ <sup>20,21)</sup>,  $\text{Mn}_{2-x}\text{Cu}_x\text{Sb}$ <sup>22)</sup> and  $\text{Mn}_2\text{Sb}_{1-x}\text{As}_x$ <sup>23)</sup> suggested that the environment around the Mn atoms and the lattice distortion play an important role in the stabilization of the magnetic state. Thought

the origin of the field-induced TTA effect is still unclear, we confirmed that the magnetic and electrical properties of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$ ,  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  could be controlled by magnetic fields and pressures without the TTA effect.

#### 4. Summary

The magnetization measurements in  $B \leq 5$  T and the initial permeability measurements under high pressures up to 1 GPa were carried out for  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$ , and the electrical resistivity was measured for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  for  $B \leq 16$  T and  $4.2 \leq T \leq 270$  K.  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  showed a first-order AFM/FRI transition at 230 K with a thermal hysteresis of 15 K. The AFM/FRI transition temperature decreased by applying magnetic field. The AFM/FRI transition temperature also decreased linearly with increasing pressures. The pressure dependence of the AFM/FRI transition temperature of  $\text{Mn}_2\text{Sb}_{0.92}\text{Ge}_{0.08}$  was estimated to be  $-5.1 \times 10^{-2} \text{ GPa}^{-1}$ . At the transition temperature, the electrical resistivity changed abruptly by 50% for  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and by 71% for  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$ . The values of the negative magnetoresistance of  $\text{Mn}_2\text{Sb}_{0.92}\text{Sn}_{0.08}$  and  $\text{Mn}_2\text{Sb}_{0.85}\text{Sn}_{0.15}$  were over 60%.

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